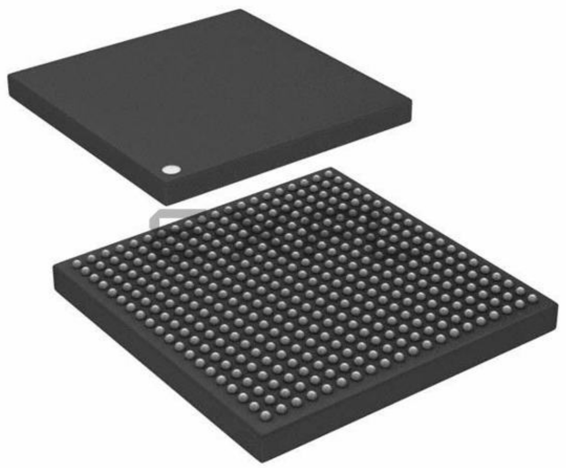

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Embedded - System On Chip (SoC): The Heart of Modern Embedded Systems

Embedded - System On Chip (SoC) refers to an integrated circuit that consolidates all the essential components of a computer system into a single chip. This includes a microprocessor, memory, and other peripherals, all packed into one compact and efficient package. SoCs are designed to provide a complete computing solution, optimizing both space and power consumption, making them ideal for a wide range of embedded applications.

What are Embedded - System On Chip (SoC)?

System On Chip (SoC) integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions, SoCs combine a central

Details	
Product Status	Active
Architecture	MCU, FPGA
Core Processor	ARM® Cortex®-M3
Flash Size	128KB
RAM Size	64KB
Peripherals	DDR
Connectivity	CANbus, Ethernet, I²C, SPI, UART/USART, USB
Speed	166MHz
Primary Attributes	FPGA - 5K Logic Modules
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	400-LFBGA
Supplier Device Package	400-VFBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/m2s005-1vfg400i

Contents

Microsemi
Power Matters.

2 IGLOO2 FPGA and SmartFusion2 SoC FPGA

Microsemi's mainstream SmartFusion®2 SoC and IGLOO®2 FPGA families integrate an industry standard 4-input lookup table-based (LUT) FPGA fabric with integrated math blocks, multiple embedded memory blocks, and high-performance SerDes communication interfaces on a single chip. Both families benefit from low-power flash technology and are the most secure and reliable FPGAs in the industry. These next generation devices offer up to 150K Logic Elements, up to 5 MBs of embedded RAM, up to 16 SerDes lanes, and up to four PCI Express Gen 2 endpoints, as well as integrated hard DDR3 memory controllers with error correction.

SmartFusion2 devices integrate an entire low-power, real-time microcontroller subsystem (MSS) with a rich set of industry-standard peripherals including Ethernet, USB, and CAN, while IGLOO2 devices integrate a high-performance memory subsystem with on-chip flash, 32 Kbyte embedded SRAM, and multiple DMA controllers.

2.1 Device Status

The following table shows the design security densities and development status of the IGLOO2 FPGA and SmartFusion2 SoC FPGA devices.

Table 1 • **IGLOO2 and SmartFusion2 Design Security Densities**

Design Security Device Densities	Status
005	Production
010, 010T	Production
025, 025T	Production
050, 050T	Production
060, 060T	Production
090, 090T	Production
150, 150T	Production

The following table shows the data security densities and development status of the IGLOO2 FPGA and SmartFusion2 SoC FPGA devices.

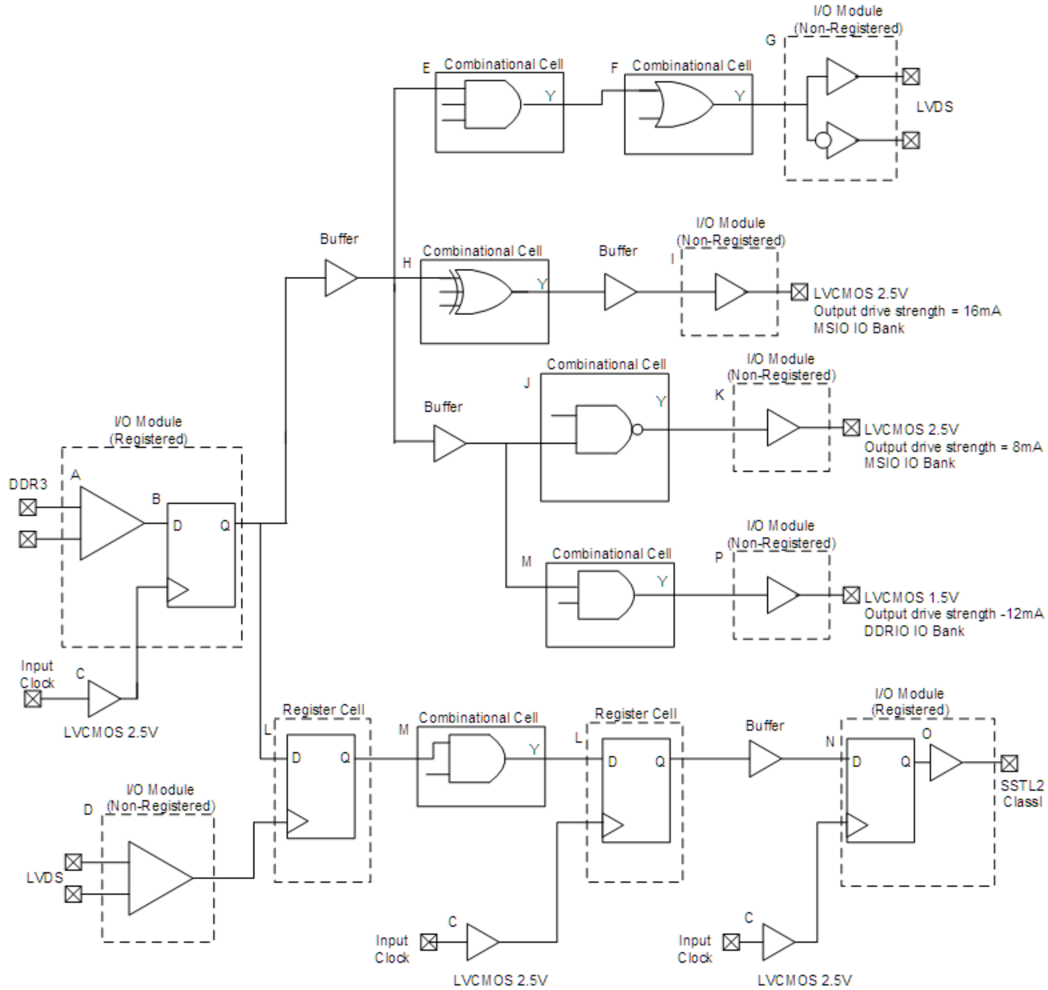
Table 2 • **IGLOO2 and SmartFusion2 Data Security Densities**

Data Security Device Densities	Status
005S	Production
010TS	Production
025TS	Production
050TS	Production
060TS	Production
090TS	Production
150TS	Production

2.3.4 Timing Model

This section describes timing model and timing parameters.

Figure 2 • **Timing Model**



The following table lists the timing model parameters in worst commercial-case conditions when T_J = 85 °C, V_{DD} = 1.14 V.

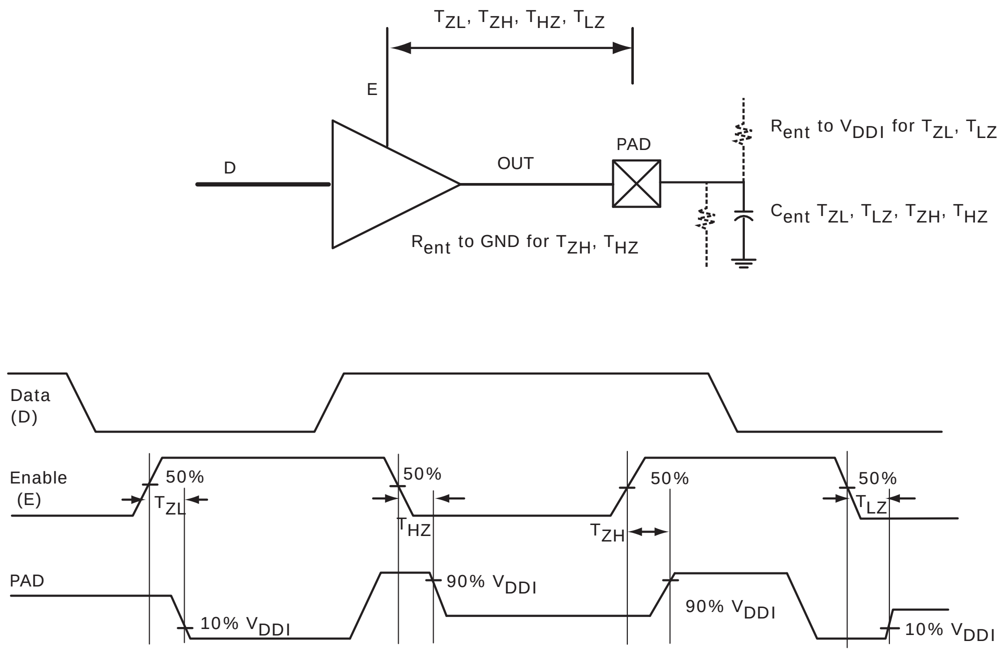
Table 17 • **Timing Model Parameters**

Index	Symbol	Description	–1	Unit	For More Information
A	T_{PY}	Propagation delay of DDR3 receiver	1.605	ns	See Table 137, page 50
B	T_{ICLKQ}	Clock-to-Q of the input data register	0.16	ns	See Table 221, page 71
	T_{ISUD}	Setup time of the input data register	0.357	ns	See Table 221, page 71
C	T_{RCKH}	Input high delay for global clock	1.53	ns	See Table 227, page 78
	T_{RCKL}	Input low delay for global clock	0.897	ns	See Table 227, page 78
D	T_{PY}	Input propagation delay of LVDS receiver	2.774	ns	See Table 167, page 56
E	T_{DP}	Propagation delay of a three-input AND gate	0.198	ns	See Table 223, page 76

2.3.5.3 Tristate Buffer and AC Loading

The tristate path for enable path loadings is described in the respective specifications. The following figure shows the methodology of characterization illustrated by the enable path test point.

Figure 5 • **Tristate Buffer for Enable Path Test Point**



2.3.5.4 I/O Speeds

This section describes the maximum data rate summary of I/O in worst-case industrial conditions. See the individual I/O standards for operating conditions.

Table 18 • **Maximum Data Rate Summary Table for Single-Ended I/O in Worst-Case Industrial Conditions**

I/O	MSIO	MSIOD	DDRIO	Unit
PCI 3.3 V	630			Mbps
LVTTL 3.3 V	600			Mbps
LVCMOS 3.3 V	600			Mbps
LVCMOS 2.5 V	410	420	400	Mbps
LVCMOS 1.8 V	295	400	400	Mbps
LVCMOS 1.5 V	160	220	235	Mbps
LVCMOS 1.2 V	120	160	200	Mbps
LPDDR-LVCMOS 1.8 V mode			400	Mbps

Table 19 • **Maximum Data Rate Summary Table for Voltage-Referenced I/O in Worst-Case Industrial Conditions**

I/O	MSIO	MSIOD	DDRIO	Unit
LPDDR			400	Mbps
HSTL1.5 V			400	Mbps
SSTL 2.5 V	510	700	400	Mbps
SSTL 1.8 V			667	Mbps
SSTL 1.5 V			667	Mbps

Table 20 • **Maximum Data Rate Summary Table for Differential I/O in Worst-Case Industrial Conditions**

I/O	MSIO	MSIOD	Unit
LVPECL (input only)	900		Mbps
LVDS 3.3 V	535		Mbps
LVDS 2.5 V	535	700	Mbps
RSDS	520	700	Mbps
BLVDS	500		Mbps
MLVDS	500		Mbps
Mini-LVDS	520	700	Mbps

Table 21 • **Maximum Frequency Summary Table for Single-Ended I/O in Worst-Case Industrial Conditions**

I/O	MSIO	MSIOD	DDRIO	Unit
PCI 3.3 V	315			MHz
LVTTL 3.3 V	300			MHz
LVCMOS 3.3 V	300			MHz
LVCMOS 2.5 V	205	210	200	MHz
LVCMOS 1.8 V	147.5	200	200	MHz
LVCMOS 1.5 V	80	110	118	MHz
LVCMOS 1.2 V	60	80	100	MHz
LPDDR– LVCMOS 1.8 V mode			200	MHz

Table 107 • **SSTL2 AC Differential Voltage Specifications**

Parameter	Symbol	Min	Max	Unit
AC input differential voltage	V_{DIFF} (AC)	0.7		V
AC differential cross point voltage	V_x (AC)	0.5 × V_{DDI} – 0.2	0.5 × V_{DDI} + 0.2	V

Table 108 • **SSTL2 Minimum and Maximum AC Switching Speeds**

Parameter	Symbol	Max	Unit	Conditions
Maximum data rate (for DDRIO I/O bank)	D_{MAX}	400	Mbps	AC loading: per JEDEC specifications
Maximum data rate (for MSIO I/O bank)	D_{MAX}	575	Mbps	AC loading: 17pF load
Maximum data rate (for MSIOD I/O bank)	D_{MAX}	700	Mbps	AC loading: 3 pF / 50 Ω load
		510	Mbps	AC loading: 17pF load

Table 109 • **SSTL2 AC Impedance Specifications**

Parameter	Typ	Unit	Conditions
Supported output driver calibrated impedance (for DDRIO I/O bank)	20, 42	Ω	Reference resistor = 150 Ω

Table 110 • **DDR1/SSTL2 AC Test Parameter Specifications**

Parameter	Symbol	Typ	Unit
Measuring/trip point for data path	V_{TRIP}	1.25	V
Resistance for enable path (T_{ZH}, T_{ZL}, T_{HZ}, T_{LZ})	R_{ENT}	2K	Ω
Capacitive loading for enable path (T_{ZH}, T_{ZL}, T_{HZ}, T_{LZ})	C_{ENT}	5	pF
Reference resistance for data test path for SSTL2 Class I (T_{DP})	RTT_TEST	50	Ω
Reference resistance for data test path for SSTL2 Class II (T_{DP})	RTT_TEST	25	Ω
Capacitive loading for data path (T_{DP})	C_{LOAD}	5	pF

AC Switching Characteristics

Worst commercial-case conditions: T_J = 85 °C, V_{DD} = 1.14 V, V_{DDI} = 2.375 V

Table 111 • **SSTL2 Receiver Characteristics for DDRIO I/O Bank (Input Buffers)**

	On-Die Termination (ODT)	T_{PY}		
		–1	–Std	Unit
Pseudo differential	None	1.549	1.821	ns
True differential	None	1.589	1.87	ns

Table 122 • **SSTL18 DC Differential Voltage Specification**

Parameter	Symbol	Min	Unit
DC input differential voltage	V_{ID} (DC)	0.3	V

Table 123 • **SSTL18 AC Differential Voltage Specifications (Applicable to DDRIO Bank Only)**

Parameter	Symbol	Min	Max	Unit
AC input differential voltage	V_{DIFF} (AC)	0.5		V
AC differential cross point voltage	V_x (AC)	$0.5 \times V_{DDI} - 0.175$	$0.5 \times V_{DDI} + 0.175$	V

Table 124 • **SSTL18 Minimum and Maximum AC Switching Speed (Applicable to DDRIO Bank Only)**

Parameter	Symbol	Max	Unit	Conditions
Maximum data rate (for DDRIO I/O bank)	D_{MAX}	667	Mbps	AC loading: per JEDEC specification

Table 125 • **SSTL18 AC Impedance Specifications (Applicable to DDRIO Bank Only)**

Parameter	Symbol	Typ	Unit	Conditions
Supported output driver calibrated impedance (for DDRIO I/O bank)	R_{REF}	20, 42	Ω	Reference resistor = 150 Ω
Effective impedance value (ODT)	R_{TT}	50, 75, 150	Ω	Reference resistor = 150 Ω

Table 126 • **SSTL18 AC Test Parameter Specifications (Applicable to DDRIO Bank Only)**

Parameter	Symbol	Typ	Unit
Measuring/trip point for data path	V_{TRIP}	0.9	V
Resistance for enable path (T_{ZH}, T_{ZL}, T_{HZ}, T_{LZ})	R_{ENT}	2K	Ω
Capacitive loading for enable path (T_{ZH}, T_{ZL}, T_{HZ}, T_{LZ})	C_{ENT}	5	pF
Reference resistance for data test path for SSTL18 Class I (T_{DP})	RTT_TEST	50	Ω
Reference resistance for data test path for SSTL18 Class II (T_{DP})	RTT_TEST	25	Ω
Capacitive loading for data path (T_{DP})	C_{LOAD}	5	pF

AC Switching Characteristics

Worst commercial-case conditions: T_J = 85 °C, V_{DD} = 1.14 V, V_{DDI} = 1.71 V

Table 127 • **DDR2/SSTL18 Receiver Characteristics for DDRIO I/O Bank with Fixed Code**

		T_{PY}		
	On-Die Termination (ODT)	**–1**	**–Std**	**Unit**
Pseudo differential	None	1.567	1.844	ns
True differential	None	1.588	1.869	ns

Table 191 • **M-LVDS AC Switching Characteristics for Receiver (for MSIOD I/O Bank - Input Buffers)**

	T_{PY}		
On-Die Termination (ODT)	**–1**	**–Std**	**Unit**
None	2.495	2.934	ns
100	2.495	2.935	ns

Table 192 • **M-LVDS AC Switching Characteristics for Transmitter (for MSIO I/O Bank - Output and Tristate Buffers)**

T_{DP}		T_{ZL}		T_{ZH}		T_{HZ}		T_{LZ}		
–1	**–Std**	**–1**	**–Std**	**–1**	**–Std**	**–1**	**–Std**	**–1**	**–Std**	**Unit**
2.258	2.656	2.348	2.762	2.334	2.746	2.123	2.497	2.125	2.5	ns

2.3.7.4 Mini-LVDS

Mini-LVDS is an unidirectional interface from the timing controller to the column drivers and is designed to the Texas Instruments Standard SLDA007A.

Mini-LVDS Minimum and Maximum Input and Output Levels

Table 193 • **Mini-LVDS Recommended DC Operating Conditions**

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage	V_{DDI}	2.375	2.5	2.625	V

Table 194 • **Mini-LVDS DC Input Voltage Specification**

Parameter	Symbol	Min	Max	Unit
DC Input voltage	V_I	0	2.925	V

Table 195 • **Mini-LVDS DC Output Voltage Specification**

Parameter	Symbol	Min	Typ	Max	Unit
DC output logic high	V_{OH}	1.25	1.425	1.6	V
DC output logic low	V_{OL}	0.9	1.075	1.25	V

Table 196 • **Mini-LVDS DC Differential Voltage Specification**

Parameter	Symbol	Min	Max	Unit
Differential output voltage swing	V_{OD}	300	600	mV
Output common mode voltage	V_{OCM}	1	1.4	V
Input common mode voltage	V_{ICM}	0.3	1.2	V
Input differential voltage	V_{ID}	100	600	mV

Table 197 • **Mini-LVDS Minimum and Maximum AC Switching Speed**

Parameter	Symbol	Max	Unit	Conditions
Maximum data rate (for MSIO I/O bank)	D_{MAX}	520	Mbps	AC loading: 2 pF / 100 Ω differential load
Maximum data rate (for MSIOD I/O bank)	D_{MAX}	700	Mbps	AC loading: 2 pF / 100 Ω differential load

Table 222 • **Output DDR Propagation Delays *(continued)***

Symbol	Description	Measuring Nodes (from, to)	–1	–Std	Unit
$T_{DDROWAL}$	Asynchronous load minimum pulse width for output DDR	C, C	0.304	0.357	ns
$T_{DDROCKMPWH}$	Clock minimum pulse width high for the output DDR	E, E	0.075	0.088	ns
$T_{DDROCKMPWL}$	Clock minimum pulse width low for the output DDR	E, E	0.159	0.187	ns

2.3.10 Logic Element Specifications

2.3.10.1 4-input LUT (LUT-4)

The IGLOO2 and SmartFusion2 SoC FPGAs offer a fully permutable 4-input LUT. In this section, timing characteristics are presented for a sample of the library. For more details, see *SmartFusion2 and IGLOO2 Macro Library Guide*.

Figure 14 • **LUT-4**

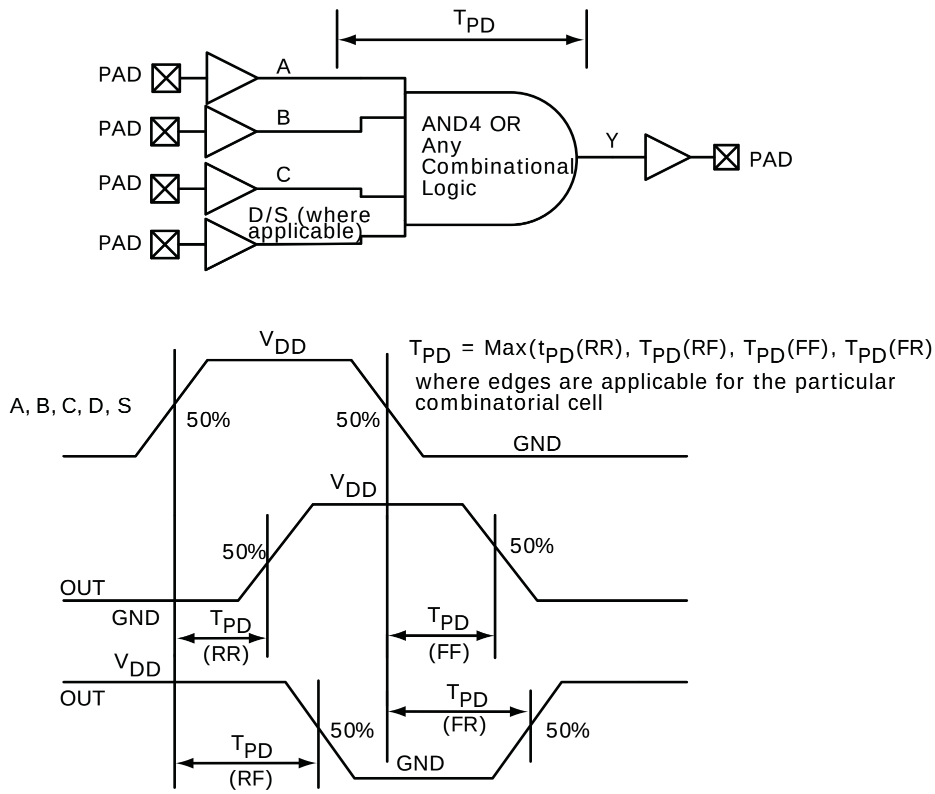


Table 232 • RAM1K18 – Dual-Port Mode for Depth × Width Configuration 2K × 9 (continued)

		–1		–Std		
Parameter	**Symbol**	**Min**	**Max**	**Min**	**Max**	**Unit**
Address setup time	T_{ADDRSU}	0.475		0.559		ns
Address hold time	T_{ADDRHD}	0.274		0.322		ns
Data setup time	T_{DSU}	0.336		0.395		ns
Data hold time	T_{DHD}	0.082		0.096		ns
Block select setup time	T_{BLKSU}	0.207		0.244		ns
Block select hold time	T_{BLKHD}	0.216		0.254		ns
Block select to out disable time (when pipelined register is disabled)	T_{BLK2Q}		1.529		1.799	ns
Block select minimum pulse width	T_{BLKMPW}	0.186		0.219		ns
Read enable setup time	T_{RDESU}	0.485		0.57		ns
Read enable hold time	T_{RDEHD}	0.071		0.083		ns
Pipelined read enable setup time (A_DOUT_EN, B_DOUT_EN)	$T_{RDPLESU}$	0.248		0.291		ns
Pipelined read enable hold time (A_DOUT_EN, B_DOUT_EN)	$T_{RDPLEHD}$	0.102		0.12		ns
Asynchronous reset to output propagation delay	T_{R2Q}		1.514		1.781	ns
Asynchronous reset removal time	T_{RSTREM}	0.506		0.595		ns
Asynchronous reset recovery time	T_{RSTREC}	0.004		0.005		ns
Asynchronous reset minimum pulse width	T_{RSTMPW}	0.301		0.354		ns
Pipelined register asynchronous reset removal time	$T_{PLRSTREM}$	–0.279		–0.328		ns
Pipelined register asynchronous reset recovery time	$T_{PLRSTREC}$	0.327		0.385		ns
Pipelined register asynchronous reset minimum pulse width	$T_{PLRSTMPW}$	0.282		0.332		ns
Synchronous reset setup time	T_{SRSTSU}	0.226		0.265		ns
Synchronous reset hold time	T_{SRSTHD}	0.036		0.043		ns
Write enable setup time	T_{WESU}	0.415		0.488		ns
Write enable hold time	T_{WEHD}	0.048		0.057		ns
Maximum frequency	F_{MAX}		400		340	MHz

The following table lists the RAM1K18 – dual-port mode for depth × width configuration 4K × 4 in worst commercial-case conditions when T_J = 85 °C, V_{DD} = 1.14 V.

Table 233 • RAM1K18 – Dual-Port Mode for Depth × Width Configuration 4K × 4

		–1		–Std		
Parameter	**Symbol**	**Min**	**Max**	**Min**	**Max**	**Unit**
Clock period	T_{CY}	2.5		2.941		ns
Clock minimum pulse width high	$T_{CLKMPWH}$	1.125		1.323		ns
Clock minimum pulse width low	$T_{CLKMPWL}$	1.125		1.323		ns
Pipelined clock period	T_{PLCY}	2.5		2.941		ns
Pipelined clock minimum pulse width high	$T_{PLCLKMPWH}$	1.125		1.323		ns

Table 248 • **2 Step IAP Programming (eNVM Only)**

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	137536	2	37	5	Sec
010	274816	4	76	11	Sec
025	274816	4	78	10	Sec
050	278528	3	85	9	Sec
060	268480	5	76	22	Sec
090	544496	10	152	43	Sec
150	544496	10	153	44	Sec

Table 249 • **2 Step IAP Programming (Fabric and eNVM)**

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	439296	6	56	11	Sec
010	842688	11	100	21	Sec
025	1497408	19	113	32	Sec
050	2695168	32	136	48	Sec
060	2686464	43	137	70	Sec
090	4190208	68	236	115	Sec
150	6682768	109	286	162	Sec

Table 250 • **SmartFusion2 Cortex-M3 ISP Programming (Fabric Only)**

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	302672	6	19	8	Sec
010	568784	10	26	14	Sec
025	1223504	21	39	29	Sec
050	2424832	39	60	50	Sec
060	2418896	44	65	54	Sec
090	3645968	66	90	79	Sec
150	6139184	108	140	128	Sec

Table 251 • **SmartFusion2 Cortex-M3 ISP Programming (eNVM Only)**

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	137536	3	42	4	Sec
010	274816	4	82	7	Sec
025	274816	4	82	8	Sec
050	278528	4	80	8	Sec
060	268480	6	80	8	Sec
090	544496	10	157	15	Sec

The following table lists the programming times in worst-case conditions when T_J = 100 °C, V_{DD} = 1.14 V. External SPI flash part# AT25DF641-s3H is used during this measurement.

Table 256 • **JTAG Programming (Fabric Only)**

M2S/M2GL Device	Image size Bytes	Program	Verify	Unit
005	302672	44	10	Sec
010	568784	50	18	Sec
025	1223504	73	26	Sec
050	2424832	88	54	Sec
060	2418896	99	54	Sec
090	3645968	135	126	Sec
150	6139184	177	193	Sec

Table 257 • **JTAG Programming (eNVM Only)**

M2S/M2GL Device	Image size Bytes	Program	Verify	Unit
005	137536	61	4	Sec
010	274816	100	9	Sec
025	274816	100	9	Sec
050	2,78,528	106	8	Sec
060	268480	98	8	Sec
090	544496	176	15	Sec
150	544496	177	15	Sec

Table 258 • **JTAG Programming (Fabric and eNVM)**

M2S/M2GL Device	Image size Bytes	Program	Verify	Unit
005	439296	71	11	Sec
010	842688	129	20	Sec
025	1497408	142	35	Sec
050	2695168	184	59	Sec
060	2686464	180	70	Sec
090	4190208	288	147	Sec
150	6682768	338	231	Sec

2.3.14 Math Block Timing Characteristics

The fundamental building block in any digital signal processing algorithm is the multiply-accumulate function. Each IGLOO2 and SmartFusion2 SoC math block supports 18×18 signed multiplication, dot product, and built-in addition, subtraction, and accumulation units to combine multiplication results efficiently. The following table lists the math blocks with all registers used in worst commercial-case conditions when T_J = 85 °C, V_{DD} = 1.14 V.

Table 268 • **Math Blocks with all Registers Used**

		–1		–Std		
Parameter	**Symbol**	**Min**	**Max**	**Min**	**Max**	**Unit**
Input, control register setup time	T_{MISU}	0.149		0.176		ns
Input, control register hold time	T_{MIHD}	1.68		1.976		ns
CDIN input setup time	$T_{MOCDINSU}$	0.185		0.218		ns
CDIN input hold time	$T_{MOCDINHD}$	0.08		0.094		ns
Synchronous reset/enable setup time	$T_{MSRSTENSU}$	–0.419		–0.493		ns
Synchronous reset/enable hold time	$T_{MSRSTENHD}$	0.011		0.013		ns
Asynchronous reset removal time	$T_{MARSTREM}$	0		0		ns
Asynchronous reset recovery time	$T_{MARSTREC}$	0.088		0.104		ns
Output register clock to out delay	T_{MOCQ}		0.232		0.273	ns
CLK minimum period	T_{MCLKMP}	2.245		2.641		ns

The following table lists the math blocks with input bypassed and output registers used in worst commercial-case conditions when T_J = 85 °C, V_{DD} = 1.14 V.

Table 269 • **Math Block with Input Bypassed and Output Registers Used**

		–1		–Std		
Parameter	**Symbol**	**Min**	**Max**	**Min**	**Max**	**Unit**
Output register setup time	T_{MOSU}	2.294		2.699		ns
Output register hold time	T_{MOHD}	1.68		1.976		ns
CDIN input setup time	$T_{MOCDINSU}$	0.115		0.136		ns
CDIN input hold time	$T_{MOCDINHD}$	–0.444		–0.522		ns
Synchronous reset/enable setup time	$T_{MSRSTENSU}$	–0.419		–0.493		ns
Synchronous reset/enable hold time	$T_{MSRSTENHD}$	0.011		0.013		ns
Asynchronous reset removal time	$T_{MARSTREM}$	0		0		ns
Asynchronous reset recovery time	$T_{MARSTREC}$	0.014		0.017		ns
Output register clock to out delay	T_{MOCQ}		0.232		0.273	ns
CLK minimum period	T_{MCLKMP}	2.179		2.563		ns

Table 276 • Cryptographic Block Characteristics *(continued)*

Service	Conditions	Timing	Unit
SHA256	512 bits	540	kbps
	1024 bits	780	kbps
	2048 bits	950	kbps
	24 kbits	1140	kbps
HMAC	512 bytes	820	kbps
	1024 bytes	890	kbps
	2048 bytes	930	kbps
	24 kbytes	980	kbps
KeyTree		1.8	ms
Challenge-response	PUF = OFF	25	ms
	PUF = ON	7	ms
ECC point multiplication		590	ms
ECC point addition		8	ms

1. Using cypher block chaining (CBC) mode.

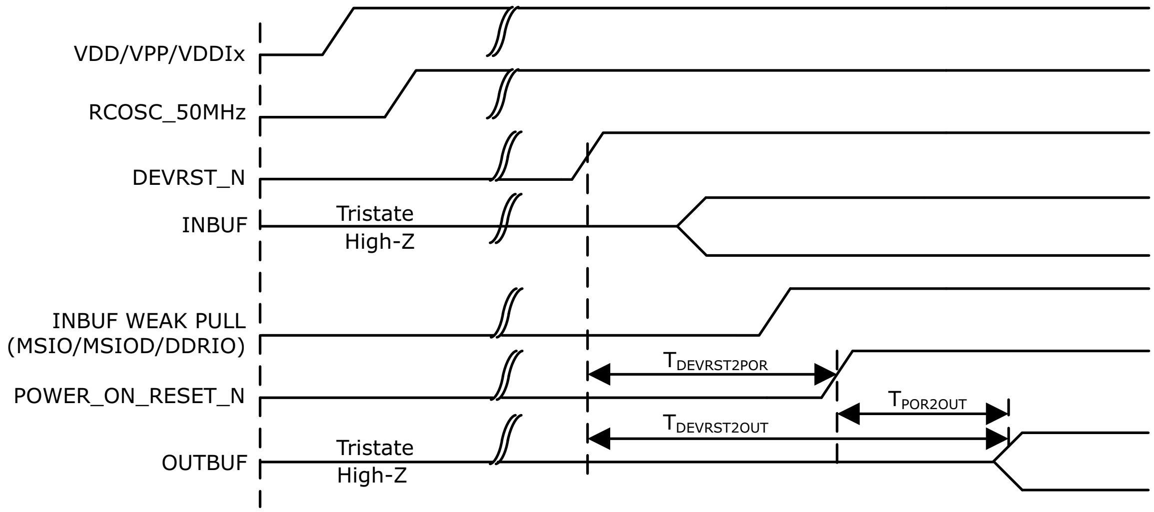
2.3.19 Crystal Oscillator

The following table describes the electrical characteristics of the crystal oscillator in the IGLOO2 FPGA and SmartFusion2 SoC FPGAs.

Table 277 • Electrical Characteristics of the Crystal Oscillator – High Gain Mode (20 MHz)

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Operating frequency	FXTAL		20		MHz	
Accuracy	ACCXTAL			0.0047	%	005, 010, 025, 050, 060, and 090 devices
				0.0058	%	150 devices
Output duty cycle	CYCXTAL		49–51	47–53	%	
Output period jitter (peak to peak)	JITPERXTAL		200	300	ps	
Output cycle to cycle jitter (peak to peak)	JITCYCXTAL		200	300	ps	010, 025, 050, and 060 devices
			250	410	ps	150 devices
			250	550	ps	005 and 090 devices
Operating current	IDYNXTAL		1.5		mA	010, 050, and 060 devices
			1.65		mA	005, 025, 090, and 150 devices
Input logic level high	VIHXTAL	0.9 V_{PP}			V	
Input logic level low	VILXTAL			0.1 V_{PP}	V	

Figure 20 • **DEVRST_N to Functional Timing Diagram for IGLOO2**



2.3.27 Flash*Freeze Timing Characteristics

The following table lists the Flash*Freeze entry and exit times in worst-case industrial conditions when T_J = 100 °C, V_{DD} = 1.14 V.

Table 293 • **Flash*Freeze Entry and Exit Times**

		Entry/Exit Timing FCLK = 100MHz		Entry/Exit Timing FCLK = 3 MHz		
Parameter	**Symbol**	**005, 010, 025, 060, 090, and 150**	**050**	**All Devices**	**Unit**	**Conditions**
Entry time	TFF_ENTRY	160	150	320	µs	eNVM and MSS/HPMS PLL = ON
		215	200	430	µs	eNVM and MSS/HPMS PLL= OFF
Exit time with respect to the MSS PLL Lock	TFF_EXIT	100	100	140	µs	eNVM and MSS/HPMS PLL = ON during F*F
		136	120	190	µs	eNVM = ON and MSS/HPMS PLL = OFF during F*F and MSS/HPMS PLL turned back on at exit
		200	200	285	µs	eNVM and MSS/HPMS PLL = OFF during F*F and both are turned back on at exit
		200	200	285	µs	eNVM = OFF and MSS/HPMS PLL = ON during F*F and eNVM turned back on at exit

2.3.30 SerDes Electrical and Timing AC and DC Characteristics

PCIe is a high-speed, packet-based, point-to-point, low-pin-count, serial interconnect bus. The IGLOO2 and SmartFusion2 SoC FPGAs has up to four hard high-speed serial interface blocks. Each SerDes block contains a PCIe system block. The PCIe system is connected to the SerDes block.

The following table lists the transmitter parameters in worst-case industrial conditions when T_J = 100 °C, V_{DD} = 1.14 V.

Table 296 • **Transmitter Parameters**

Symbol	Description	Min	Max	Unit
VTX-DIFF-PP	Differential swing (2.5 Gbps, 5.0 Gbps)	0.8	1.2	V
VTX-CM-AC-P	Output common mode voltage (2.5 Gbps)		20	mV
VTX-CM-AC-PP	Output common mode voltage (5.0 Gbps)		100	mV
VTX-RISE-FALL	Rise and fall time (20% to 80%, 2.5 Gbps)	0.125		UI
	Rise and fall time (20% to 80%, 5.0 Gbps)	0.15		UI
ZTX-DIFF-DC	Output impedance–differential	80	120	Ω
LTX-SKEW	Lane-to-lane TX skew within a SerDes block (2.5 Gbps)		500 ps + 2 UI	ps
	Lane-to-lane TX skew within a SerDes block (5.0 Gbps)		500 ps + 4 UI	ps
RLTX-DIFF	Return loss differential mode (2.5 Gbps)	–10		dB
	Return loss differential mode (5.0 Gbps) 0.05 GHz to 1.25 GHz	–10		dB
	1.25 GHz to 2.5 GHz	–8		dB
RLTX-CM	Return loss common mode (2.5 Gbps, 5.0 Gbps)	–6		dB
TX-LOCK-RST	Transmit PLL lock time from reset		10	µs
VTX-AMP	100 mV setting	90	150	mV
	400 mV setting	320	480	mV
	800 mV setting	660	940	mV
	1200 mV setting	950	1400	mV

The following table lists the receiver pa in worst-case industrial conditions when T_J = 100 °C, V_{DD} = 1.14 V.

Table 297 • **Receiver Parameters**

Symbol	Description	Min	Typ	Max	Unit
VRX-IN-PP-CC	Differential input peak-to-peak sensitivity (2.5 Gbps)	0.238		1.2	V
	Differential input peak-to-peak sensitivity (2.5 Gbps, de-emphasized)	0.219		1.2	V
	Differential input peak-to-peak sensitivity (5.0 Gbps)	0.300		1.2	V
	Differential input peak-to-peak sensitivity (5.0 Gbps, de-emphasized)	0.300		1.2	V
VRX-CM-AC-P	Input common mode range (AC coupled)			150	mV
ZRX-DIFF-DC	Differential input termination	80	100	120	Ω
REXT	External calibration resistor	1,188	1,200	1,212	Ω
CDR-LOCK-RST	CDR relock time from reset			15	µs
RLRX-DIFF	Return loss differential mode (2.5 Gbps)	–10			dB
	Return loss differential mode (5.0 Gbps) 0.05 GHz to 1.25 GHz	–10			dB
	1.25 GHz to 2.5 GHz	–8			dB
RLRX-CM	Return loss common mode (2.5 Gbps, 5.0 Gbps)	–6			dB
RX-CID[1]	CID limit PCIe Gen1/2			200	UI
VRX-IDLE-DET-DIFF-PP	Signal detect limit	65		175	mV

1. AC-coupled, BER = e^{-12}, using synchronous clock.

Table 298 • **SerDes Protocol Compliance**

Protocol	Maximum Data Rate (Gbps)	–1	–Std
PCIe Gen 1	2.5	Yes	Yes
PCIe Gen 2	5.0	Yes	
XAUI	3.125	Yes	
Generic EPCS	3.2	Yes	
Generic EPCS	2.5	Yes	Yes

2.3.31.3 Serial Peripheral Interface (SPI) Characteristics

This section describes the DC and switching of the SPI interface. Unless otherwise noted, all output characteristics given are for a 35 pF load on the pins and all sequential timing characteristics are related to SPI_x_CLK. For timing parameter definitions, see Figure 22, page 128.

The following table lists the SPI characteristics in worst-case industrial conditions when T_J = 100 °C, V_{DD} = 1.14 V

Table 305 • **SPI Characteristics for All Devices**

Symbol	Description	Min	Typ	Max	Unit	Conditions
SPIFMAX	Maximum operating frequency of SPI interface			20	MHz	
sp1	SPI_[0|1]_CLK minimum period					
	SPI_[0|1]_CLK = PCLK/2	12			ns	
	SPI_[0|1]_CLK = PCLK/4	24.1			ns	
	SPI_[0|1]_CLK = PCLK/8	48.2			ns	
	SPI_[0|1]_CLK = PCLK/16	0.1			µs	
	SPI_[0|1]_CLK = PCLK/32	0.19			µs	
	SPI_[0|1]_CLK = PCLK/64	0.39			µs	
	SPI_[0|1]_CLK = PCLK/128	0.77			µs	
sp2	SPI_[0|1]_CLK minimum pulse width high					
	SPI_[0|1]_CLK = PCLK/2	6			ns	
	SPI_[0|1]_CLK = PCLK/4	12.05			ns	
	SPI_[0|1]_CLK = PCLK/8	24.1			ns	
	SPI_[0|1]_CLK = PCLK/16	0.05			µs	
	SPI_[0|1]_CLK = PCLK/32	0.095			µs	
	SPI_[0|1]_CLK = PCLK/64	0.195			µs	
	SPI_[0|1]_CLK = PCLK/128	0.385			µs	
sp3	SPI_[0|1]_CLK minimum pulse width low					
	SPI_[0|1]_CLK = PCLK/2	6			ns	
	SPI_[0|1]_CLK = PCLK/4	12.05			ns	
	SPI_[0|1]_CLK = PCLK/8	24.1			ns	
	SPI_[0|1]_CLK = PCLK/16	0.05			µs	
	SPI_[0|1]_CLK = PCLK/32	0.095			µs	
	SPI_[0|1]_CLK = PCLK/64	0.195			µs	
	SPI_[0|1]_CLK = PCLK/128	0.385			µs	
sp4	SPI_[0|1]_CLK, SPI_[0|1]_DO, SPI_[0|1]_SS rise time (10%–90%)[1]		2.77		ns	I/O Configuration: LVCMOS 2.5 V–8 mA AC loading: 35 pF Test conditions: Typical voltage, 25 °C